

# COMPOSITE EQUIVALENT SC RESISTORS AND THEIR STUDY

Dr. Rajeev Kumar Singh<sup>1</sup>

<sup>1</sup>Bhagwant University, Ajmer, Rajasthan, India

## ABSTRACT

*The recent developments of switched capacitor (SC) the field of network analysis and synthesis. In the present study the equivalent resistors have been produced by SC networks. The study of such resistors is made implemented with op-amp. The characteristics of the network is compared with that of conventional one. Precision high order filters are widely used in various types of electronic. Precision high order filters are widely used in various types of electronic equipment such as telecommunication and other voice band systems. Monolithic implementation of these low frequency filters requires the realization of long time constants in small silicon area; and the realization of transfer functions that are insensitive to parameter variations*

**Keyword:** - SC, Filters, Electronic, Op-amp etc.

## 1. INTRODUCTION

A resistor is a passive two-terminal electrical component that implements electrical resistance as a circuit element. In electronic circuits, resistors are used to reduce current flow, adjust signal levels, to divide voltages, bias active elements, and terminate transmission lines, among other uses. High-power resistors that can dissipate many watts of electrical power as heat, may be used as part of motor controls, in power distribution systems, or as test loads for generators. Fixed resistors have resistances that only change slightly with temperature, time or operating voltage. Variable resistors can be used to adjust circuit elements (such as a volume control or a lamp dimmer), or as sensing devices for heat, light, humidity, force, or chemical activity.

Resistors are common elements of electrical networks and electronic circuits and are ubiquitous in electronic equipment. Practical resistors as discrete components can be composed of various compounds and forms. Resistors are also implemented within integrated circuits.

The electrical function of a resistor is specified by its resistance: common commercial resistors are manufactured over a range of more than nine orders of magnitude. The nominal value of the resistance falls within the manufacturing tolerance, indicated on the component.

A composite material (also called a composition material or shortened to composite, which is the common name) is a material made from two or more constituent materials with significantly different physical or chemical properties that, when combined, produce a material with characteristics different from the individual components. The individual components remain separate and distinct within the finished structure, differentiating composites from mixtures and solid solutions.[1] The new material may be preferred for many reasons: common examples include materials which are stronger, lighter, or less expensive when compared to traditional materials.

The discovery of new idea of SC networks which have 'special characteristics of long time constant and insensitive to component variations have attracted many scientists working in the field of circuit theory. Precision high order filters are widely used in various types of electronic

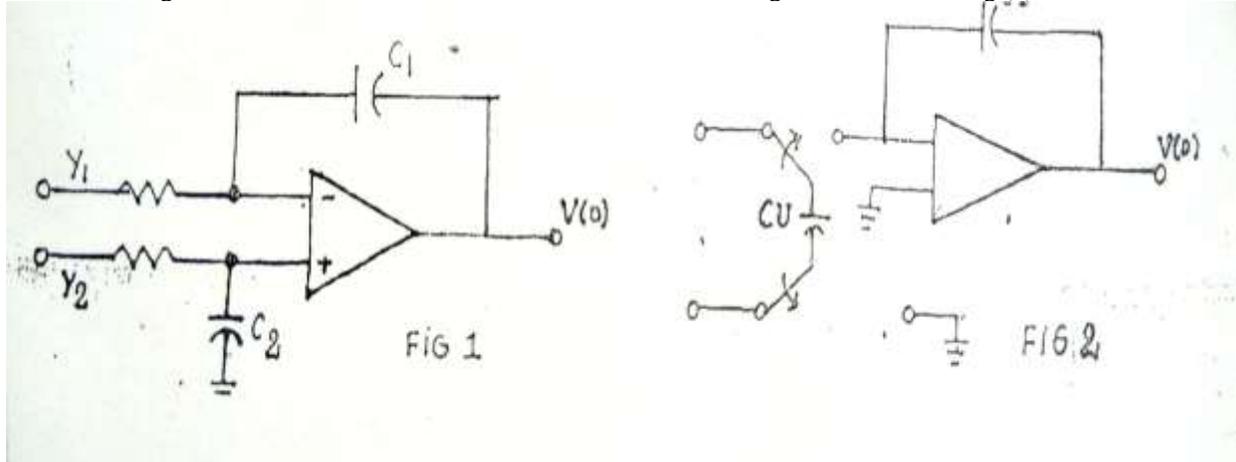
equipment such as telecommunication and other voice band systems. Monolithic implementation of these low frequency filters requires the realization of long time constants in small silicon area; and the realization of transfer functions that are insensitive to parameter variations [1]. The conventional active filters implemented with thin films or hybrid techniques do not meet these requirements. Therefore they are not suitable for many application [2].

In past decades Op-amp. has been a building block of active resistance capacitance (RC) networks, such as active filters, integrator and differentiators etc. The resistors to be used with active networks may be implemented with SC

networks [3]. The SC networks implemented with implemented with SC networks [3]. The SC networks i implemented with op amp. has brought a revolutionary change in network technology and research work [4][5][6]. Moreover the parasitics presented by input capacitance to op amps. induce errors and considerably complicate the design procedures. Intensive study shows that composite SC networks have overcome these difficulties of circuit designer to a great extent [7].

**2. EQUIVALENT SC NETWORK OF DIFFERENTIAL**

The circuit diagram of RC active network known as differential RC integrator is shown in fig (1).



The output of the differential integrator may be obtained by applying simple network theorems. Applying Kirchoffs Current law (LCL) at node (A)

$$V_1 Y_1 - V_A (\gamma_1 + j\omega C_1) + V_o j\omega C_1 = 0$$

$$\text{Or, } V_A = \frac{\gamma_1 v_1 + v_o j\omega C_1}{\gamma_1 + j\omega C_1} \quad \dots \quad 1$$

Again Applying KCL at node B one gets

$$(v_2 - V_B)\gamma_2 + (0 - v_B) j\omega C_2 = 0$$

$$\text{Or, } V_B = \frac{v_2 \gamma_2}{\gamma_2 + j\omega C_2} \quad \dots \quad 2$$

Applying ideal op amp.  $V_A = V_B$

Therefore, from equations (1), (2), (3)

$$V_o = \frac{\gamma_1 + j\omega C_1}{j\omega C_1} \left[ \frac{v_2 \gamma_2}{\gamma_2 + j\omega C_2} - \frac{v_1 \gamma_1}{\gamma_1 + j\omega C_1} \right] \quad \dots \quad 4$$

To make the network suitable for diffractions integrator  $y_1 = y_2$

$$j\omega C_1 = j\omega C_2 \quad \dots \quad 5$$

This yields

$$V_o = \frac{\gamma}{j\omega C} (V_2 - V_1) \quad \text{since } \gamma = 1/R$$

So  $V_o = \frac{1}{j\omega CR} (V_{o2} - V_{o1}) e^{j\omega t}$

Or,  $V_o = \frac{1}{RC} \int (V_{o2} - V_{o1}) e^{j\omega t} dt \quad \text{since } RC = T$

Or,  $V_o(t) = \frac{1}{T} \int_0^T (V_{o2} - V_{o1}) e^{j\omega t} dt$

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The network is Known as differential integrator

The differential gain may be written as

$$A_d = \frac{-j}{RC\omega} = \frac{-j}{\omega T} \quad \text{7}$$

Where  $T = RC$

$$A_d = \frac{1}{\omega T}$$

$$A_d = \frac{1}{RC\omega} = \frac{1}{T\omega}$$

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The numerical value of R=5K ohm,C=1 nF the differential gain is given in the table

$\omega$	0.1	0.2	0.3	0.4	0.5	0.6	0.7	0.8	0.9	1.0
$A_d$	$2 \times 10^6$	$10^6$	$.66 \times 10^6$	$.5 \times 10^6$	$4 \times 10^5$	$3 \times 10^5$	$2.8 \times 10^5$	$2.5 \times 10^5$	$2.2 \times 10^5$	$2 \times 10^5$

It is found that the differential integrator serves as low pass filter.

### 3. SC NETWORK

The circuit diagram of SC integrator is shown in the figure No.(2). It is operated with two phase non overlapping Clocks. sample phase the switched are thrown to left and the difference between Voltage  $V_1$  and  $V_2$  is coupled and stored on  $C_u$ . During integration phase the switches are thrown to right and difference of Voltages is sealed and stored on C. By switching  $C_u$  at high clock rate relative to pass band frequencies an equivalent resistance is obtained [9].

$$R_{eq} = 1/f_c C_u \quad \text{11}$$

Where  $f_c$  = Clock Frequency

The integrator gain constant of frequency given by

$$w = 1/R_{eq} f_c C_1 = f_c (C_u/C_1) \quad \text{12}$$

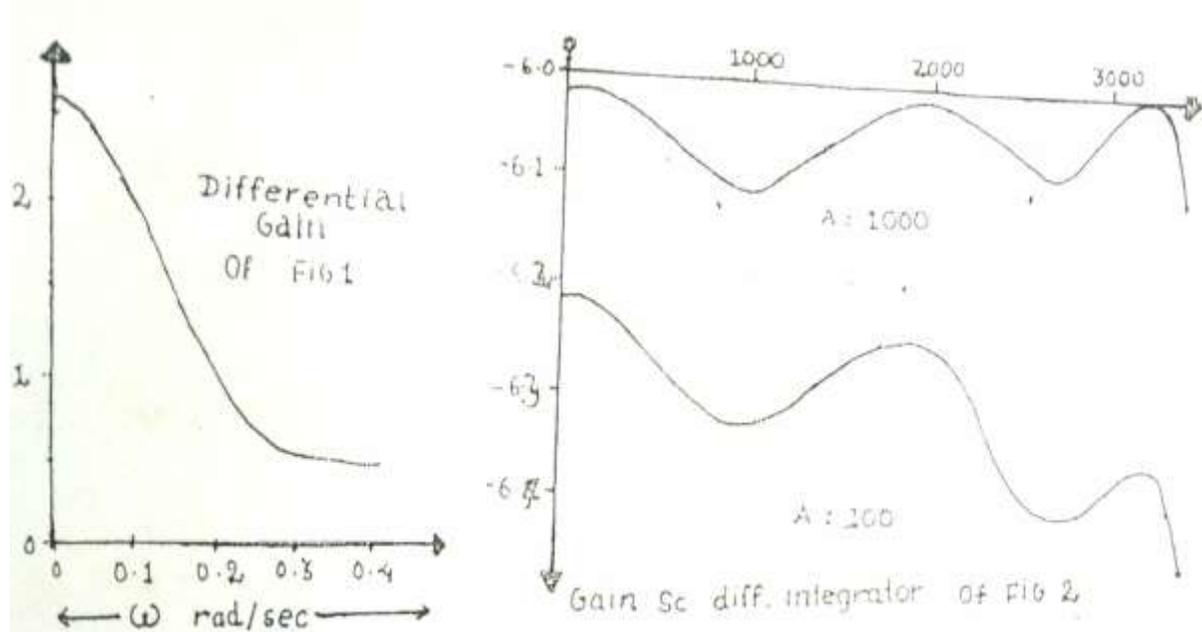
The switched capacitor realizes a very large resistance in very small chip . From eqn. (11) it can be seen that by switching a IP-F Capacitor at 100 KHZ an equivalent resistance of 10 M ohm is realized in an area of only about 5 mil<sup>2</sup> for  $C_u$  plus a few additional square mils for the minimum geometry.

MOSFET SWITCH Transistor. If this equivalent resistor is used in Conjunction with  $C_1$  to  $C_u$  a gain constant of  $10^4$  rad/sec is obtained. Since the gain constant in (12) is determined by a ratio of monolithic capacitors, high matching accuracy and excellent temperature stability are obtained in monolithic MOS implementation . [8, 9,10,11,12,13].

The gain of the switched capacitor integrator with op-amp is given in fig. 3.

The plotting is performed by PSPICE Program.

From the graph it is evident that nature of low pass filter is modified switched capacitor resistor implemented with op-amp.



#### 4. CONCLUSIONS

In this paper a simple method has been adopted to present the SC resistor and their implementation with op-amp. This approach for realizing MOS Switched Capacitor integrators with gain constants determined by capacitor ratio achieves excellent temperature stability. The SC networks implemented with active filter network produces precise frequency response. The intensive study of response curve shows that the circuit is insensitive to its component variations. This approach may also be applicable to band pass filter. By using weighted integration capacitor arrays programmable networks may be designed. It can be seen that by switching a IP-F Capacitor at 100 KHZ an equivalent resistance of 10 M ohm is realized in an area of only about 5 mil<sup>2</sup> for Cu plus a few additional square mils for the minimum geometry.

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## BOGRAPHIES



Dr. (Lt.) Rajeev Kumar Singh Associate Professor Department of Physics in Bhagwant University, Ajmer. I have published many Research Papers and attending many conferences. He is also published many book in Physics.

